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Energy transfer in poly(vinyl alcohol)-encapsulated Mn-doped ZnS quantum dots

Thanh Phuong Nguyen^{a,b}, Quang Vinh Lam^c, Thi Bich Vu^{d,e}

^aFaculty of Graphic Arts and Media, HCMC University of Technology and Education, No. 1 Vo Van Ngan Street, Linh Chieu Ward, Thu Duc District, Ho Chi Minh City 700000, Vietnam

^bUniversity of Science, Viet Nam National University Ho Chi Minh City, No. 227 Nguyen Van Cu Street., Ward 4, District 5, Ho Chi Minh City 700000, Vietnam

^cViet Nam National University Ho Chi Minh City, Linh Trung Ward, Thu Duc District, Ho Chi Minh City 700000, Vietnam

^dInstitute of Physics, Viet Nam Academy of Science and Technology, No. 10, Dao Tan, Thu Le, Ba Dinh, Ha Noi 100000, Vietnam

^eDuy Tan University, No. 254 Nguyen Van Linh Street, Thanh Khe District, Da Nang City, Vietnam

Correspondence should be addressed to Thanh Phuong Nguyen; phuongnt@hcmute.edu.vn

Abstract

Poly(vinyl alcohol) (PVA)-encapsulated Mn²⁺-doped ZnS quantum dots (PVA-ZnS:Mn²⁺ QDs) synthesized at 80 °C in air. The structural property was investigated using X-ray powder diffraction (XRD). The XRD analysis shows that the ZnS:Mn²⁺ QDs possessed a zinc blende structure and the complexes of ZnS:Mn²⁺ QDs with PVA molecules have been formed. The photoexcitation energy transfer is found and investigated between PVA molecules and ZnS:Mn²⁺ QDs using characterization techniques such as Fourier transform infrared spectroscopy (FTIR), UV-vis absorption spectroscopy, photoluminescence excitation (PLE) and photoluminescence (PL) spectroscopy. The studied results show the photoluminescence enhancement of the Mn²⁺ ⁴T₁(G) – ⁶A₁(S) emission intensity is due to the efficient energy transfer process from the ZnS host lattice and PVA capping molecules to Mn²⁺ centers. Moreover, Förster resonance energy transfer (FRET) efficiency from PVA molecules to the Mn²⁺ center within PVA-ZnS:Mn²⁺ QDs is about 20.28%.

Keywords: Energy transfer; Mn²⁺-doped ZnS; Quantum dots; Photoluminescence

1. Introduction

Semiconductor quantum dots (QDs) have attracted great interest in recent years due to their unique optical properties and potential applications. Among II-VI semiconductors, zinc sulfide (ZnS) is relatively a non-toxic material when compared to Cd-based QDs. ZnS has a wide direct bandgap of 3.6 eV, a small exciton Bohr radius of 2.5 nm [1] and particularly suitable as a host material for a large variety of luminescent ions such as Ag⁺, Cu²⁺, Mn²⁺, Eu³⁺, Sm³⁺, Tb³⁺. Recently, these semiconductor QDs have been systematically investigated, particularly Mn²⁺ doped ZnS quantum dots (ZnS:Mn²⁺ QDs), and have attained many successes although many debates still exist.

Additionally, the ZnS:Mn²⁺ QDs can be applied in a variety of fields such as optoelectronics [2-5], fluorescent ink [6] and fluorescent labeling agents [7,8]. In particular, the hybrid polymer-semiconductor quantum dots are becoming increasingly attractive because of a large number of applications in thin film electroluminescent (EL) devices [3,5]. Recently, the poly(vinyl alcohol) (PVA)-capped ZnS:Mn²⁺ QDs [9-12], poly(vinyl pyrrolidone) (PVP)-capped ZnS and PVP-capped ZnS:Mn²⁺ QDs [13] have attracted great attention. Poly(vinyl alcohol) (PVA) is chosen as a good host material for QDs due to its excellent thermo-stability, transparency over the whole visible spectrum, chemical resistance, high mechanical strength and good adhesion to hydrophilic surfaces. Additionally, hybrid ZnS:Mn²⁺ quantum dot-PVA systems have the inherent characteristics of PVA polymer matrices and unique optical of ZnS:Mn²⁺ QDs [12,14].

However, most of the previous work on PVA-encapsulated Mn²⁺-doped ZnS QDs is focused on understanding and solving the tasks of optimum Mn²⁺ doping content, PVA concentration and thermal stability of PVA-capped ZnS:Mn²⁺ nanoparticles [9-12]. Viswanath and co-workers [9] reported that the PL color from the poly(vinyl alcohol) (PVA) capped Mn²⁺ doped ZnS nanocrystals can be tuned from UV to near infrared (IR) region. Very recently, Thai et al. [12] studied the effect of PVA on the photoluminescence enhancement of Mn²⁺ ions in ZnS:Mn²⁺/PVA nanoparticles. Besides, Kumar et al. [13] indicated the process of energy transfer from the poly(vinyl pyrrolidone) (PVP) surface adsorbate to the dopant Mn²⁺ ions in ZnS nanocrystals resulting in efficient orange-red emission. Anni and co-worker [15] demonstrated efficient Förster resonant energy transfer from a blue-emitting conjugated polymer to colloidal CdSe/ZnS core/shell quantum dots in hybrid films.

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